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(Use several)

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FOREIGN PATENT DOCUMENTS

[illegible]

Sf		
	1	DATA SHEET FOR IXYS CORPORATION, SI BASED POWER SCHOTTKY RECTIFIER, PART NUMBER DSS 20-0015B
Sr	2	DATA SHEET FOR INTERNATIONAL RECTIFIER, SI BASED SHOTTKY RECTIFIER, PART NUMBER 11DQ09
	3	M. MEHROTRA, B.J. BALIGA, "THE TRENCH MOS BARRIER SHOTTKY (TMBS) RECTIFIER", INTERNATIONAL ELECTRON DEVICE MEETING, 1993.
Sfc	4	L.P. HUNTER, "PHYSICS OF SEMICONDUCTOR MATERIALS, DEVICES, AND CIRCUITS", SEMICONDUCTOR DEVICES, P. 3-2 - 3-7 (1970)
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Examiner	<i>Shonmaggler</i>	Date Considered	<i>3/11/02.</i>
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.